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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/620,459	07/17/2003	Nobuo Suzuki	0649-0902P	9186
	7590 01/16/2007 ART KOLASCH & BIRO	EXAMINER		
PO BOX 747	OH WA 22040 0747	•	YODER III, CHRISS S	
FALLS CHURCH, VA 22040-0747			ART UNIT	PAPER NUMBER
			2622	
SHORTENED STATUTOR	Y PERIOD OF RESPONSE	NOTIFICATION DATE	DELIVERY MODE ·	
3 MOI	UTUC	01/16/2007	FLECTRONIC	

Please find below and/or attached an Office communication concerning this application or proceeding.

If NO period for reply is specified above, the maximum statutory period will apply and will expire 6 MONTHS from the mailing date of this communication.

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Notice of the Office communication was sent electronically on above-indicated "Notification Date" to the following e-mail address(es):

mailroom@bskb.com

		Application No.	Applicant(s)		
		10/620,459	SUZUKI ET AL.		
Office Action Summary		Examiner	Art Unit		
	-	Chriss S. Yoder, III	2622		
	The MAILING DATE of this communication ap				
	Period for Reply				
WHIC - Exten after: - If NO - Failur Any re	CRTENED STATUTORY PERIOD FOR REPLE HEVER IS LONGER, FROM THE MAILING DESIGNS of time may be available under the provisions of 37 CFR 1. SIX (6) MONTHS from the mailing date of this communication. Period for reply is specified above, the maximum statutory period to reply within the set or extended period for reply will, by statutely received by the Office later than three months after the mailing dipatent term adjustment. See 37 CFR 1.704(b).	PATE OF THIS COMMUNICATION 136(a). In no event, however, may a reply be timwill apply and will expire SIX (6) MONTHS from e, cause the application to become ABANDONE	N. sely filed the mailing date of this communication. D (35 U.S.C. § 133).		
Status					
1)⊠	Responsive to communication(s) filed on 17 J	<u>uly 2003</u> .			
2a)	This action is FINAL . 2b)⊠ This action is non-final.				
3)	☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is				
closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.					
Dispositi	on of Claims				
5)□ 6)⊠ 7)□	Claim(s) <u>1-4</u> is/are pending in the application. 4a) Of the above claim(s) is/are withdra Claim(s) is/are allowed. Claim(s) <u>1-4</u> is/are rejected. Claim(s) is/are objected to. Claim(s) are subject to restriction and/o				
Application	on Papers				
10) 🖾 -	The specification is objected to by the Examina The drawing(s) filed on 30 September 2003 is Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct The oath or declaration is objected to by the E	are: a) accepted or b) ≥ objected or b) ≥ objected or b) ≥ objected in abeyance. See the cition is required if the drawing(s) is objection is required if the drawing(s) is objection.	e 37 CFR 1.85(a). ected to. See 37 CFR 1.121(d).		
Priority u	nder 35 U.S.C. § 119				
 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 					
2) Notice 3) Inform	e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO-948) nation Disclosure Statement(s) (PTO/SB/08) r No(s)/Mail Date	4) Interview Summary Paper No(s)/Mail Da 5) Notice of Informal P 6) Other:	nte		

Application/Control Number: 10/620,459 Page 2

Art Unit: 2622

DETAILED ACTION

Drawings

The drawings were received on September 30, 2003. These drawings are not acceptable.

Figure 3 should be designated by a legend such as --Prior Art-- because only that which is old is illustrated. See MPEP § 608.02(g). Corrected drawings in compliance with 37 CFR 1.121(d) are required in reply to the Office action to avoid abandonment of the application. The replacement sheet(s) should be labeled "Replacement Sheet" in the page header (as per 37 CFR 1.84(c)) so as not to obstruct any portion of the drawing figures. If the changes are not accepted by the examiner, the applicant will be notified and informed of any required corrective action in the next Office action. The objection to the drawings will not be held in abeyance.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

- (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 1. Claims 1-3 are rejected under 35 U.S.C. 103(a) as being unpatentable over Koike et al. (US Patent # 4,514,766) in view of Yamada (US Patent # 6,236,434) and further in view of Harada (US Patent # 6,211,915).

Art Unit: 2622

Page 3

2. In regard to claim 1, note Koike discloses the use of a solid-state image pick-up device having a plurality of photoelectric converting devices arranged in a row direction and a column direction orthogonal thereto over a surface of a semiconductor substrate (figure 2: 1), comprising a vertical transfer section for transferring a charge from the photoelectric converting device in the column direction (figure 2: 2), a horizontal transfer section for transferring a charge from the vertical transfer section in the row direction (figure 2: 3'), and an output section for outputting a signal corresponding to a charge transferred through the horizontal transfer section (figure 1: 4), the vertical transfer section includes a plurality of vertical transfer channels formed on the semiconductor substrate corresponding to the photoelectric converting devices provided in the column direction, a plurality of vertical transfer electrodes formed to cross each of the vertical transfer channels as seen on a plane, and a charge reading region for reading a charge of the photoelectric converting device onto the vertical transfer channels (figure 2: the transfer channel is considered to be path 2, the transfer electrodes are only partially illustrated by 5-1 and 5-2, and the charge reading region is considered to be the arrow output from each pixel), the charge reading regions of the photoelectric converting devices which are adjacent to each other in the column direction are formed between the vertical transfer channels which are different from each other (figure 2: adjacent pixels in the same column are output to separate vertical transfer channels in opposite directions).

Therefore, it can be seen that the Koike device lacks the use of a plurality of high-sensitivity photoelectric converting devices arranged like a tetragonal grid in the

Art Unit: 2622

row direction and the column direction orthogonal thereto and serving to carry out a photoelectric conversion having a relatively high sensitivity, and a plurality of low-sensitivity photoelectric converting devices arranged like the tetragonal grid in the row direction and the column direction orthogonal thereto and serving to carry out a photoelectric conversion having a relatively low sensitivity, wherein the high and low sensitivity photoelectric converting device are arranged at an equal array pitch in positions shifted by 1/2 of the array pitch from each other in both the row and column direction, vertical transfer channels that take a winding shape extended wholly in the column direction between the photoelectric converting devices, and vertical transfer electrodes that take a winding shape extended wholly in the row direction between the photoelectric converting devices.

Yamada discloses the use of a solid-state image pick-up device wherein the photoelectric converting device are arranged at an equal array pitch in positions shifted by 1/2 of the array pitch from each other in both the row and column direction (figure 1), vertical transfer channels that take a winding shape extended wholly in the column direction between the photoelectric converting devices (column 3, line 63- column 4, line 16 and figure 1: 16-17), and vertical transfer electrodes that take a winding shape extended wholly in the row direction between the photoelectric converting devices (column 6, lines 14-40 and figure 8: 39-42). Yamada teaches that the use of a solid-state image pick-up device wherein the photoelectric converting device are arranged at an equal array pitch in positions shifted by 1/2 of the array pitch from each other in both the row and column direction, vertical transfer channels that take a winding shape

Art Unit: 2622

extended wholly in the column direction between the photoelectric converting devices, and vertical transfer electrodes that take a winding shape extended wholly in the row direction between the photoelectric converting devices is preferred in order to reduce distance between adjacent columns and thereby increase the sensor resolution (column 4, lines 50-64). Therefore, it would have been obvious to one of ordinary skill in the art to modify the Koike device to include the use of a solid-state image pick-up device wherein the photoelectric converting device are arranged at an equal array pitch in positions shifted by 1/2 of the array pitch from each other in both the row and column direction, vertical transfer channels that take a winding shape extended wholly in the column direction between the photoelectric converting devices, and vertical transfer electrodes that take a winding shape extended wholly in the row direction between the photoelectric converting devices is preferred in order to reduce distance between adjacent columns and thereby increase the sensor resolution, as suggested by Yamada.

Harada discloses the use of a plurality of high-sensitivity photoelectric converting and a plurality of low-sensitivity photoelectric converting devices serving to carry out a photoelectric conversion having a relatively high and low sensitivity (column 1, lines 20-30). Harada teaches that the use of a plurality of high-sensitivity photoelectric converting and a plurality of low-sensitivity photoelectric converting devices serving to carry out a photoelectric conversion having a relatively high and low sensitivity is preferred in order to widen the dynamic range of the imaging device (column 1, lines 20-30). Therefore, it would have been obvious to one of ordinary skill in the art to modify

the Koike device to include the use of a plurality of high-sensitivity photoelectric converting and a plurality of low-sensitivity photoelectric converting devices serving to carry out a photoelectric conversion having a relatively high and low sensitivity is preferred in order to widen the dynamic range of the imaging device, as suggested by Harada.

3. In regard to claim 2, note the primary device of Koike in view of Yamada and Harada discloses the use of a solid-state image pick-up device having a plurality of photoelectric converting devices, as claimed in claim 1 above.

Therefore, it can be seen that the primary device lacks the use of four vertical transfer electrodes are corresponding to one photoelectric converting device and are driven by vertical transfer pulses having eight phases together with the four vertical transfer electrodes corresponding to other photoelectric converting devices which are adjacent to each other in the column direction. Official Notice is taken that the concepts and advantages of using four vertical transfer electrodes provided corresponding to one photoelectric converting device and are driven by vertical transfer pulses having eight phases together with the four vertical transfer electrodes corresponding to other photoelectric converting devices which are adjacent to each other in the column direction are notoriously well known and expected in the art. Therefore, it would have been obvious to one of ordinary skill in the art to modify the primary device to include the use of four vertical transfer electrodes provided for each pixel in that are driven by

vertical transfer pulses having eight phases in order to increase the transfer speed and capacity of the imaging device.

4. In regard to claim 3, note the primary device of Koike in view of Yamada and Harada discloses the use of a solid-state image pick-up device having a plurality of photoelectric converting devices, as claimed in claim 1 above.

Therefore, it can be seen that the primary device lacks the use of two vertical transfer electrodes are corresponding to one photoelectric converting device and are driven by vertical transfer pulses having four phases together with the two vertical transfer electrodes corresponding to other photoelectric converting devices which are adjacent to each other in the column direction. Official Notice is taken that the concepts and advantages of using two vertical transfer electrodes provided corresponding to one photoelectric converting device and are driven by vertical transfer pulses having four phases together with the two vertical transfer electrodes corresponding to other photoelectric converting devices which are adjacent to each other in the column direction are notoriously well known and expected in the art. Therefore, it would have been obvious to one of ordinary skill in the art to modify the primary device to include the use of two vertical transfer electrodes provided for each pixel in that are driven by vertical transfer pulses having four phases in order to increase the transfer speed and capacity of the imaging device.

Art Unit: 2622

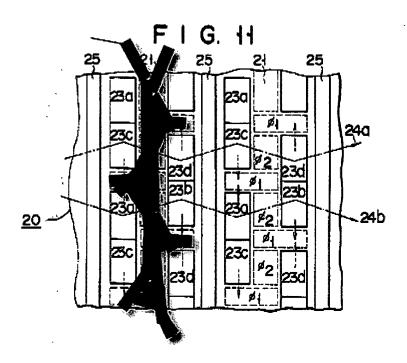
5. Claim 4 is rejected under 35 U.S.C. 103(a) as being unpatentable over Sekine et al. (US Patent # 4,336,556) in view of Yamada (US Patent # 6,236,434) and further in view of Harada (US Patent # 6,211,915).

Page 8

6. In regard to claim 4, note Sekine discloses the use of a solid-state image pick-up device having a plurality of photoelectric converting devices arranged in a row direction and a column direction orthogonal thereto over a surface of a semiconductor substrate (figure 11: 23), comprising a vertical transfer section for transferring a charge from the photoelectric converting device in the column direction (figure 11: 21), a horizontal transfer section for transferring a charge from the vertical transfer section in the row direction (figure 4: 26), and an output section for outputting a signal corresponding to a charge transferred through the horizontal transfer section (figure 4: 6), the vertical transfer section includes a plurality of vertical transfer channels formed on the semiconductor substrate corresponding to the photoelectric converting devices provided in the column direction, a plurality of vertical transfer electrodes formed to cross each of the vertical transfer channels as seen on a plane, and a charge reading region for reading a charge of the photoelectric converting device onto the vertical transfer channels (figure 11: the transfer channel is considered to be path 21, the transfer electrodes are only partially illustrated by Φ1 and Φ2, and the charge reading region is considered to be the arrow output from each pixel), the vertical transfer channel takes such a shape as to connect two winding shapes extended wholly in the column direction between the photoelectric converting devices (figure 11: 21 is considered to extend in both the left and right directions in a winding pattern connected at electrode Φ1; an

Art Unit: 2622

example can be seen below), and that the respective vertical transfer channels are shared for the transfer of the charges from two adjacent columns (figure 11: 21, Φ1 and Φ2).



Therefore, it can be seen that the Sekine device lacks the use of a plurality of high-sensitivity photoelectric converting devices arranged like a tetragonal grid in the row direction and the column direction orthogonal thereto and serving to carry out a photoelectric conversion having a relatively high sensitivity, and a plurality of low-sensitivity photoelectric converting devices arranged like the tetragonal grid in the row direction and the column direction orthogonal thereto and serving to carry out a photoelectric conversion having a relatively low sensitivity, wherein the high and low sensitivity photoelectric converting device are arranged at an equal array pitch in positions shifted by 1/2 of the array pitch from each other in both the row and column

Art Unit: 2622

direction, vertical transfer electrodes that take a winding shape extended wholly in the row direction between the photoelectric converting devices, and that the pixels from adjacent columns that share a respective vertical transfer channel are of high and low sensitivity.

Yamada discloses the use of a solid-state image pick-up device wherein the photoelectric converting device are arranged at an equal array pitch in positions shifted by 1/2 of the array pitch from each other in both the row and column direction (figure 1) and vertical transfer electrodes that take a winding shape extended wholly in the row direction between the photoelectric converting devices (column 6, lines 14-40 and figure 8: 39-42). Yamada teaches that the use of a solid-state image pick-up device wherein the photoelectric converting device are arranged at an equal array pitch in positions shifted by 1/2 of the array pitch from each other in both the row and column direction and vertical transfer electrodes that take a winding shape extended wholly in the row direction between the photoelectric converting devices is preferred in order to reduce distance between adjacent columns and thereby increase the sensor resolution (column 4, lines 50-64). Therefore, it would have been obvious to one of ordinary skill in the art to modify the Koike device to include the use of a solid-state image pick-up device wherein the photoelectric converting device are arranged at an equal array pitch in positions shifted by 1/2 of the array pitch from each other in both the row and column direction and vertical transfer electrodes that take a winding shape extended wholly in the row direction between the photoelectric converting devices is preferred in order to

Art Unit: 2622

reduce distance between adjacent columns and thereby increase the sensor resolution, as suggested by Yamada.

Page 11

Harada discloses the use of a plurality of high-sensitivity photoelectric converting and a plurality of low-sensitivity photoelectric converting devices serving to carry out a photoelectric conversion having a relatively high and low sensitivity pixels in different columns (column 1, lines 20-30 and figure 4). Harada teaches that the use of a plurality of high-sensitivity photoelectric converting and a plurality of low-sensitivity photoelectric converting devices serving to carry out a photoelectric conversion having a relatively high and low sensitivity in different columns is preferred in order to widen the dynamic range of the imaging device (column 1, lines 20-30). Therefore, it would have been obvious to one of ordinary skill in the art to modify the Koike device to include the use of a plurality of high-sensitivity photoelectric converting and a plurality of low-sensitivity photoelectric converting devices serving to carry out a photoelectric conversion having a relatively high and low sensitivity in different columns is preferred in order to widen the dynamic range of the imaging device, as suggested by Harada.

Conclusion

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

US005283451A: note the use of an imaging device having different phases for image transfer.

Art Unit: 2622

US006760071B1: note the use of an imaging device having different phases for image transfer.

US006583818B1: note the use of an imaging device having different phases for image transfer.

US006690421B1: note the use of an image sensor having pixels of the same column that are output to different transfer channels.

US005306906A: note the use of winding transfer channels.

US004242700: note the use of combined transfer channels.

US005051832: note the use of an imaging device having different phases for image transfer.

US004602289: note the use of pixels that are output in different directions.

US005274476A: note the use of an image sensor having pixels of the same column that are output to different transfer channels.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Chriss S. Yoder, III whose telephone number is (571) 272-7323. The examiner can normally be reached on M-F: 8 - 4:30.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Vivek Srivastava can be reached on (571) 272-7304. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Art Unit: 2622

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

CSY January 4, 2007

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Page 13